

## Product Summary

$BV_{DSS}$	$R_{DS(ON)}$ Max	$I_D$ Max $T_C = +25^\circ C$
-30V	20m $\Omega$ @ $V_{GS} = -10V$	-30A
	29m $\Omega$ @ $V_{GS} = -5V$	-30A

## Features and Benefits

- Low  $R_{DS(ON)}$  – ensures on state losses are minimized.
- Small form factor thermally efficient package enables higher density end products.
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product.
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

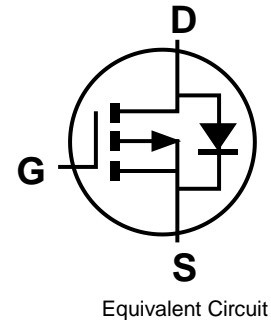
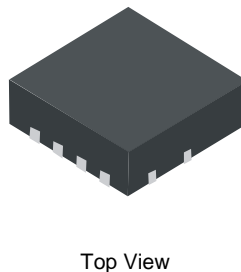
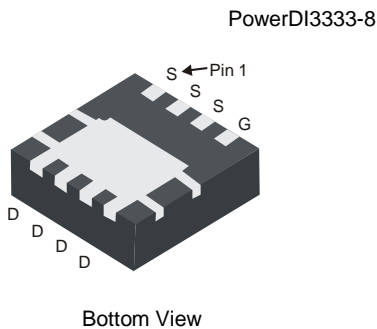
## Description and Applications

This MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

## Mechanical Data

- Case: PowerDI<sup>®</sup>3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram  
Terminals: Finish – Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208@3
- Weight: 0.03 grams (Approximate)



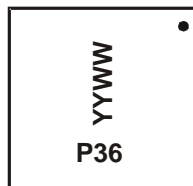
## Ordering Information (Note 4)

Part Number	Case	Packaging
DMP3036SFG-7	PowerDI3333-8	2,000/Tape & Reel
DMP3036SFG-13	PowerDI3333-8	3,000/Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information

PowerDI3333-8



P36 = Product Type Marking Code  
 YYWW = Date Code Marking  
 YY = Last Two Digits of Year (ex: 17 = 2017)  
 WW = Week Code (01 to 53)

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	-30	V	
Gate-Source Voltage	V <sub>GSS</sub>	±25	V	
Continuous Drain Current (Note 6) V <sub>GS</sub> = -10V	I <sub>D</sub>	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	-8.7 -7.0	A
Continuous Drain Current (Note 7) V <sub>GS</sub> = -10V		T <sub>C</sub> = +25°C T <sub>C</sub> = +70°C	-30 -25	A
Continuous Drain Current (Note 6) V <sub>GS</sub> = -5V	I <sub>D</sub>	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	-7.2 -5.8	A
Continuous Drain Current (Note 7) V <sub>GS</sub> = -5V		T <sub>C</sub> = +25°C T <sub>C</sub> = +70°C	-30 -24	A
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	-80	A	
Maximum Continuous Body Diode Forward Current (Note 6)	I <sub>S</sub>	-3.6	A	
Avalanche Current (Note 7) L=0.3mH	I <sub>AS</sub>	-17.5	A	
Avalanche Energy (Note 7) L=0.3mH	E <sub>AS</sub>	64	mJ	

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	P <sub>D</sub>	0.9	W	
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>θJA</sub>	Steady State	137	°C/W
		t < 10s	65	°C/W
Total Power Dissipation (Note 6)	P <sub>D</sub>	2.3	W	
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>θJA</sub>	Steady State	55	°C/W
		t < 10s	26	°C/W
Thermal Resistance, Junction to Case (Note 7)	R <sub>θJC</sub>	3.5	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS (Note 8)</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-30	-	-	V	V <sub>GS</sub> = 0V, I <sub>D</sub> = -250μA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	-	-	-1.0	μA	V <sub>DS</sub> = -30V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>	-	-	±100	nA	V <sub>GS</sub> = ±25V, V <sub>DS</sub> = 0V
<b>ON CHARACTERISTICS (Note 8)</b>						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-1.0	-2.0	-2.5	V	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = -250μA
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	-	13	20	mΩ	V <sub>GS</sub> = -10V, I <sub>D</sub> = -8A
		-	18.4	29		V <sub>GS</sub> = -5V, I <sub>D</sub> = -5A
Diode Forward Voltage	V <sub>SD</sub>	-	-0.7	-1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -1A
<b>DYNAMIC CHARACTERISTICS (Note 9)</b>						
Input Capacitance	C <sub>ISS</sub>	-	1931	-	pF	V <sub>DS</sub> = -15V, V <sub>GS</sub> = 0V, f = 1.0MHz
Output Capacitance	C <sub>OSS</sub>	-	226	-	pF	
Reverse Transfer Capacitance	C <sub>RSS</sub>	-	168	-	pF	
Gate Resistance	R <sub>g</sub>	-	10.9	-	Ω	V <sub>DS</sub> = 0V, V <sub>GS</sub> = 0V, f = 1MHz
Total Gate Charge V <sub>GS</sub> = -5V	Q <sub>g</sub>	-	8.8	-	nC	V <sub>DS</sub> = -15V, I <sub>D</sub> = -10A
Total Gate Charge V <sub>GS</sub> = -10V	Q <sub>g</sub>	-	16.5	-	nC	
Gate-Source Charge	Q <sub>gs</sub>	-	2.6	-	nC	
Gate-Drain Charge	Q <sub>gd</sub>	-	3.6	-	nC	
Turn-On Delay Time	t <sub>D(ON)</sub>	-	8.2	-	ns	V <sub>GS</sub> = -10V, V <sub>DD</sub> = -15V, R <sub>GEN</sub> = 3Ω, I <sub>D</sub> = -10A
Turn-On Rise Time	t <sub>R</sub>	-	14	-	ns	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	-	65	-	ns	
Turn-Off Fall Time	t <sub>F</sub>	-	31.6	-	ns	
Reverse Recovery Time	t <sub>RR</sub>	-	9.3	-	ns	
Reverse Recovery Charge	Q <sub>RR</sub>	-	12.2	-	nC	I <sub>F</sub> = -8A, di/dt = 500A/μs

- Notes:
- Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
  - Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
  - Thermal resistance from junction to soldering point (on the exposed drain pad).
  - Short duration pulse test used to minimize self-heating effect.
  - Guaranteed by design. Not subject to product testing.

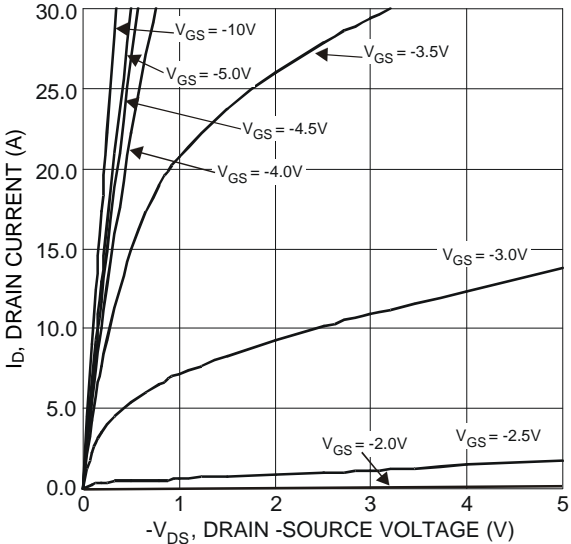


Figure 1 Typical Output Characteristics

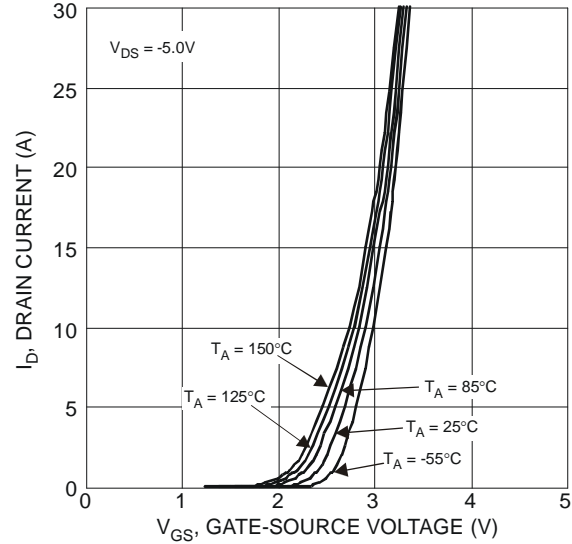


Figure 2 Typical Transfer Characteristics

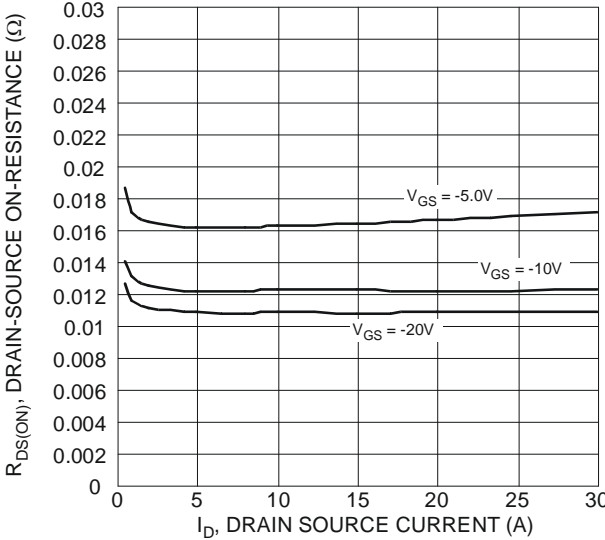


Figure 3 Typical On-Resistance vs. Drain Current and Gate Voltage

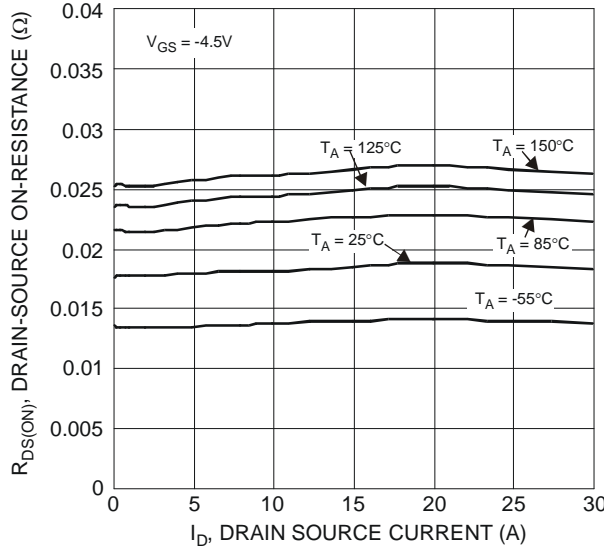


Figure 4 Typical On-Resistance vs. Drain Current and Temperature

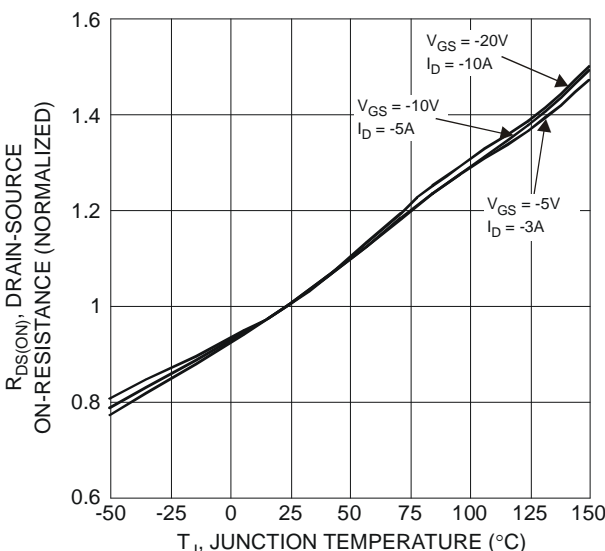


Figure 5 On-Resistance Variation with Temperature

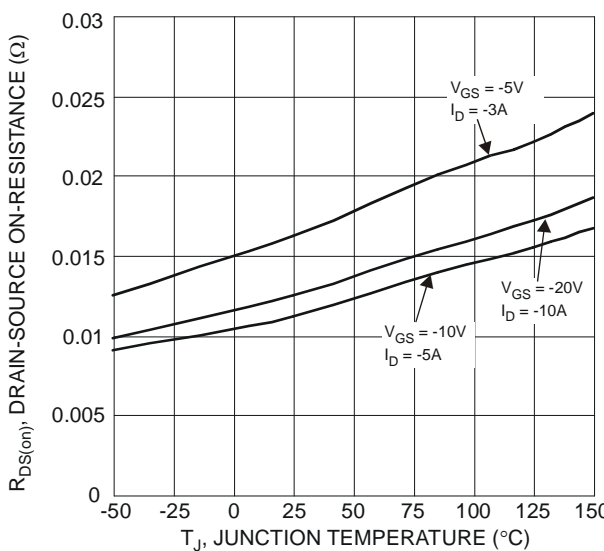


Figure 6 On-Resistance Variation with Temperature

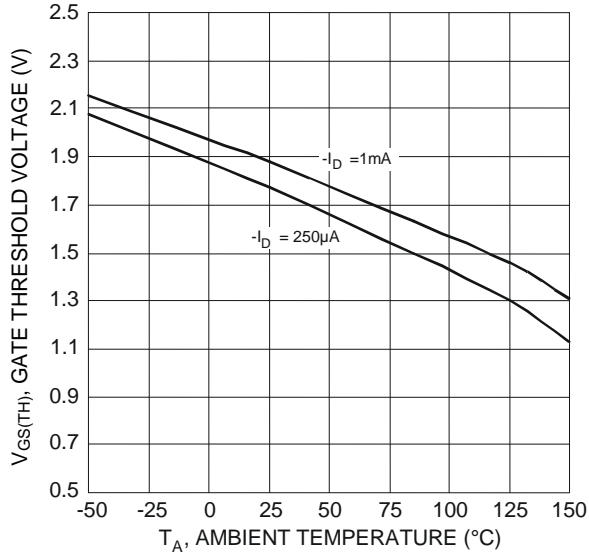


Figure 7 Gate Threshold Variation vs. Ambient Temperature

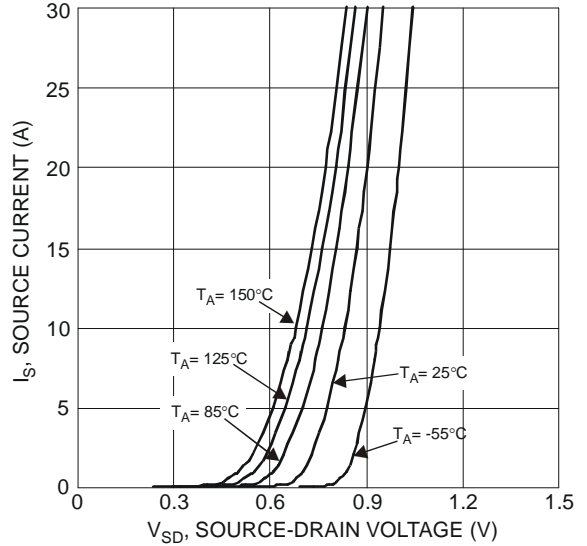


Figure 8 Diode Forward Voltage vs. Current

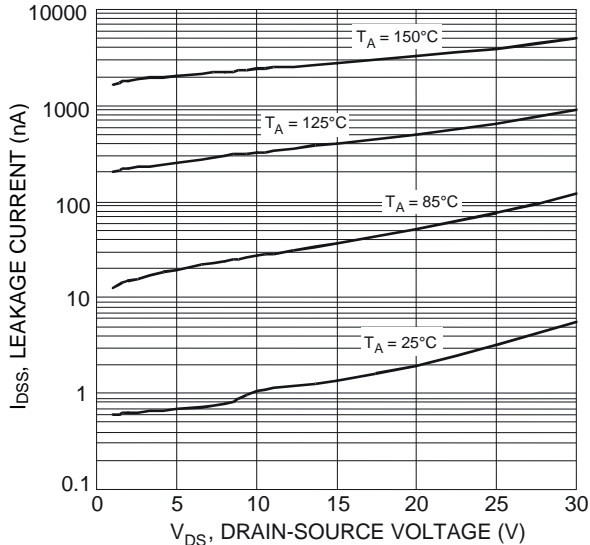


Figure 9 Typical Drain-Source Leakage Current vs. Voltage

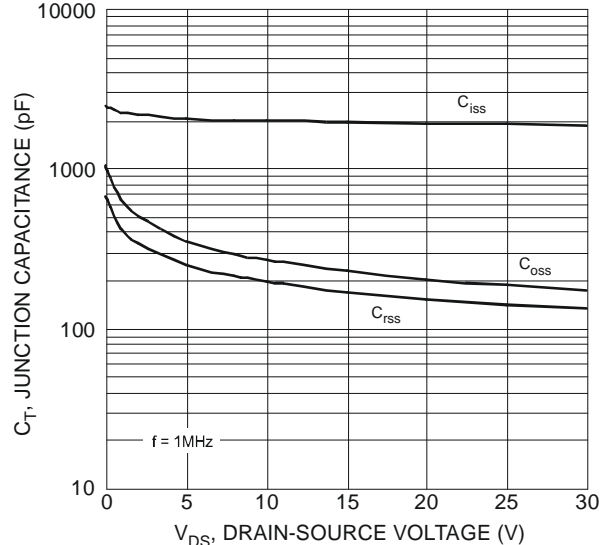


Figure 10 Typical Junction Capacitance

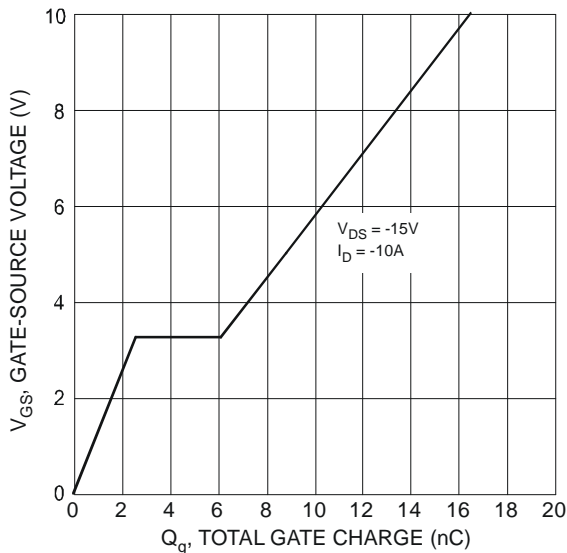


Figure 11 Gate-Charge Characteristics

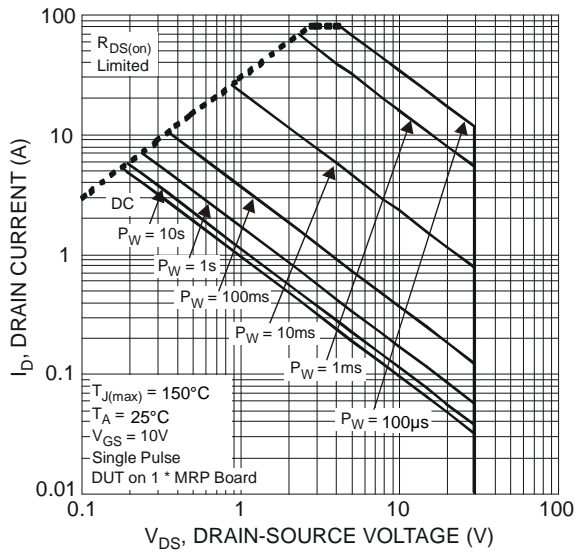


Figure 12 SOA, Safe Operation Area

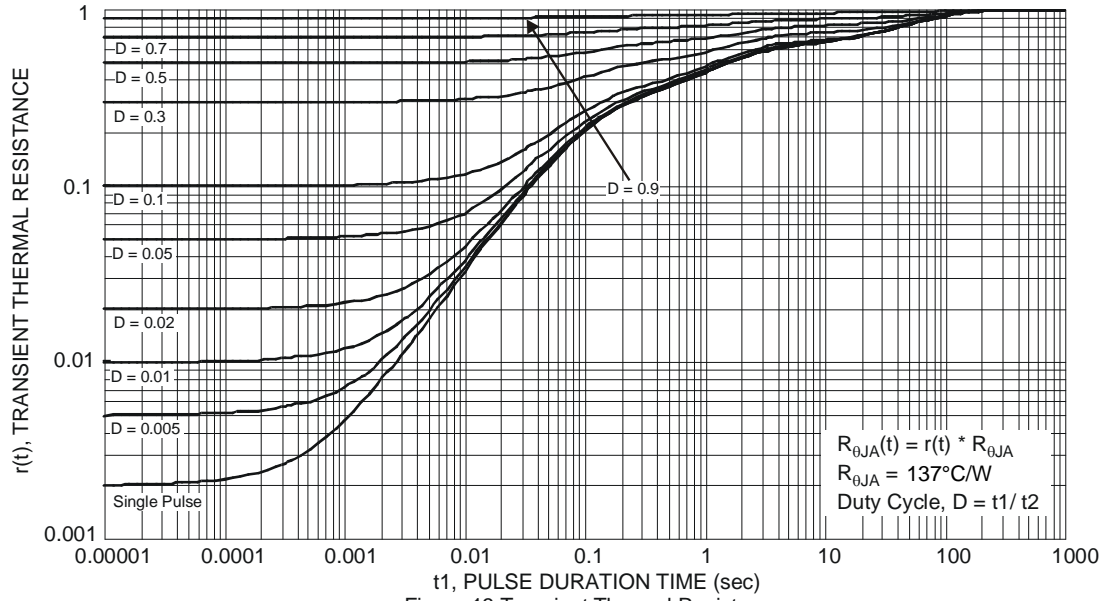


Figure 13 Transient Thermal Resistance



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